

DESCRIPTION

The MP8103 is a single supply, dual rail-to-rail output operational amplifier. This amplifier provides 600 KHz bandwidth while consuming an incredibly low $14 \mu \text{A}$ of supply current. The MP8103 can operate with a single supply voltage as low as 1.8 V. The input common mode can go below the negative rail. The maximum supply voltage is 5.5 V which allows the device to operate from $\pm 0.9 \text{V}$ to $\pm 2.75 \text{V}$ or a single supply. The MP8103 is available in an 8-pin 3mm x 5mm MSOP package.

FEATURES

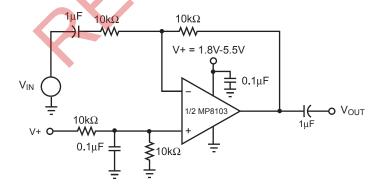
- Single Supply Operation: 1.8V to 5.5V
- 600KHz –3dB Bandwidth
- 14µA Supply Current
- Rail-to-Rail Output
- Unity-Gain Stable
- Input Common Mode to Ground
- Drives Up to 1000pF of Capacitive Loads
- High Slew Rate: 0.1V/µs
- Available in a MSOP8 Package

APPLICATIONS

- Portable Equipment
- PDAs
- Pagers
- Cordless Phones
- Handheld GPS
- Consumer Electronics
- Smoke Detector
- Portable Medical Equipment

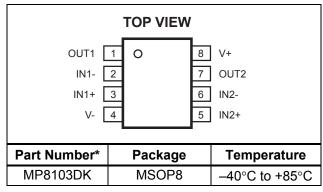
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TYPICAL APPLICATION





PACKAGE REFERENCE



For Tape & Reel, add suffix –Z (eg. MP8103DK–Z)
 For RoHS Compliant Packaging, add suffix –LF (eg. MP8103DK–LF–Z)

ABSOLUTE MAXIMUM RATINGS (1)

Supply Voltage (V+ to V-)......+6.0V Differential Input Voltage ($V_{IN+} - V_{IN-}$).....+6.0V Input Voltage ($V_{IN+} - V_{IN-}$).. $V_{IN+} + 0.3V$, $V_{IN-} - 0.3V$

Recommended Operating Conditions (2)

Supply Voltage+1.8V to +5.5V Operating Temperature-40°C to +85°C

Notes

- 1) Exceeding these ratings may damage the device.
- 2) The device is not guaranteed to function outside of its operating conditions.
- 3) Measured on approximately 1" square of 1 oz copper.

ELECTRICAL CHARACTERISTICS

 $V_+ = +5V$, $V_- = 0V$, $V_{CM} = V + /2$, $R_L = 10k\Omega$, $T_A = +25$ °C, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
Input Offset Voltage	Vos		– 5	1	+5	mV
Input Offset Voltage Temp Coefficient				15		μV/°C
Input Bias Current (4)	I _B			2		pА
Input Offset Current (4)	I _{os}			0.2		pА
Input Voltage Range	V_{CM}	CMRR > 60dB	0		3.8	V
Common-Mode Rejection Ratio	CMRR	0 < V _{CM} < 3.5V		82		dB
Power Supply Rejection Ratio	PSRR	Supply Voltage change of 1.0V		80		dB
Large Signal Voltage Gain	A _{VOL}	R_L = 100kΩ, V _{OUT} = 5.0 Peak to Peak	60	88		dB
Maximum Output Voltage Swing	V _{out}	$R_L = 10k\Omega$		V+ – 23mV		V
Minimum Output Voltage Swing	V _{OUT}	$R_L = 10k\Omega$		V– + 19mV		V
Gain-Bandwidth Product (4)	GBW	$R_L = 200k\Omega, C_L = 2pF,$ $V_{OUT} = 0$		200		KHz
-3dB Bandwidth	BW	$A_V = 1$, $C_L = 2pF$, $R_L = 1M\Omega$		600		KHz
Slew Rate (4)	SR	$A_V = 1$, $C_L = 2pF$, $R_L = 1M\Omega$		0.1		V/µs
Short Circuit Current	I _{SC}	Source		20		mA
Chort Shoult Surront		Sink		20		mA
Supply Current		No Load		14	22	μΑ

Note:

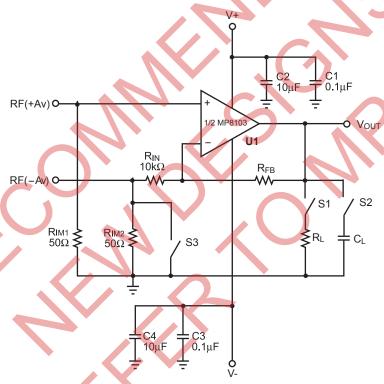
4) Guaranteed by design.



PIN FUNCTIONS

Pin#	Name	Description
1	OUT1	Output of First Op-Amp
2	IN1-	Inverting Input of First Op-Amp.
3	IN1+	Non-Inverting Input of First Op-Amp.
4	V-	Ground or Supply Return Pin.
5	IN2+	Non-Inverting Input of Second Op-Amp.
6	IN2-	Inverting Input of Second Op-Amp.
7	OUT2	Output of Second Op-Amp.
8	V+	Supply Voltage.

TEST CIRCUITS



Notes: Close S3 for positive gain. Input signal to RF(+Av) connector. The gain Av = 1 + R_{FB}/R_{IN} .

For unity gain, remove R_{IN} and short R_{FB}.

Open S3 for negative gain. Input signal to RF(-Av) connector. The gain $Av = -R_{FB}/R_{IN}$.

S1 and S2 are switches for possible resistor and capacitor load connections.

Figure 1—AC Test Circuit



TEST CIRCUITS (continued)

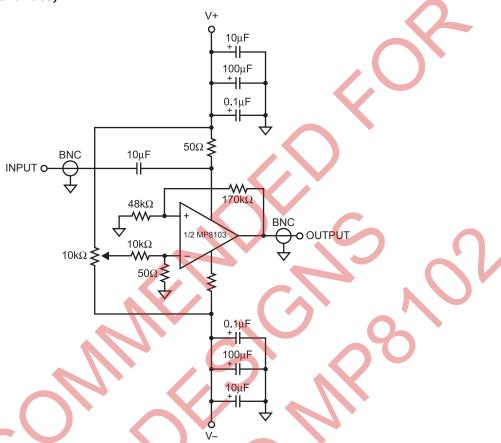


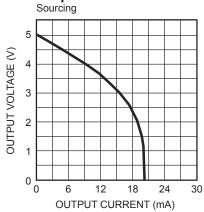
Figure 2—Positive Power Supply Rejection Ratio Measurement



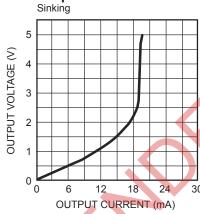
TYPICAL PERFORMANCE CHARACTERISTICS

 $T_A = +25$ °C, unless otherwise noted.

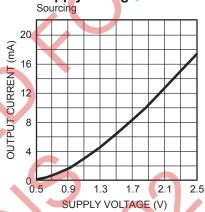
Output Voltage vs. **Output Current**



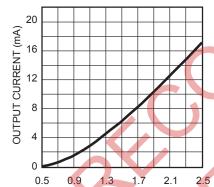
Output Voltage vs Output Current



Short Circuit Current vs Supply Voltage

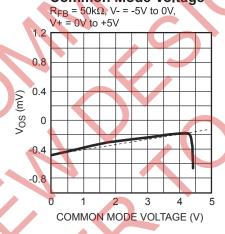


Short Circuit Current vs Supply Voltage Sinking

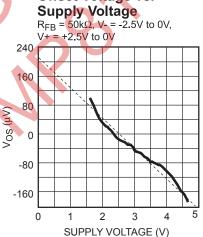


SUPPLY VOLTAGE (V)

Offset Voltage vs. **Common Mode Voltage**



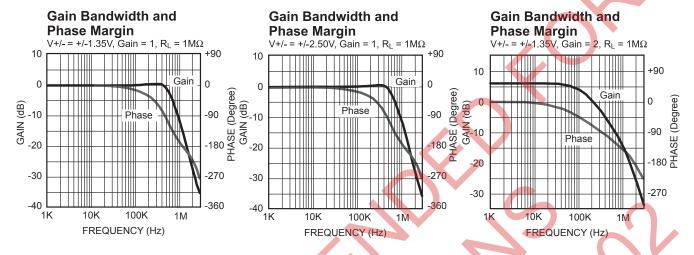
Offset Voltage vs.

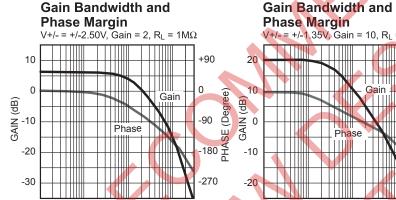


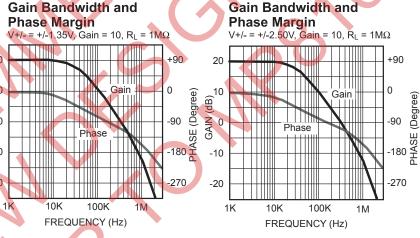


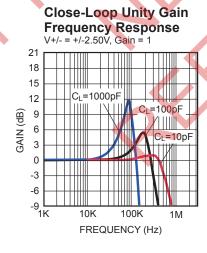
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

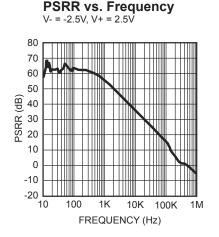
 $T_A = +25$ °C, unless otherwise noted.











1K

10K

100K

FREQUENCY (Hz)

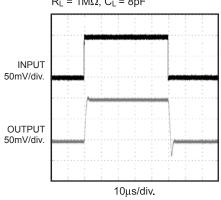


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $T_A = +25$ °C, unless otherwise noted.

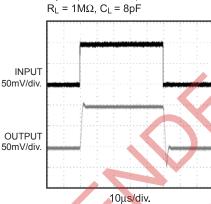
Small Signal Pulse Response

 $A_V = 1$, V+ = 2.5V, V- = -2.5V $R_L = 1M\Omega$, $C_L = 8pF$



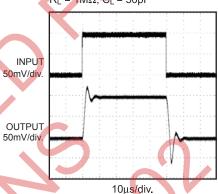
Small Signal Pulse Response

 $A_V = 1$, V + = 1.25V, V - = -1.25V



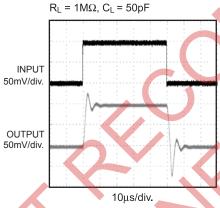
Small Signal Pulse Response

 $A_V = 1$, V + = 2.5V, V - = -2.5V $R_L = 1M\Omega$, $C_L = 50pF$



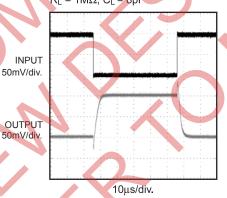
Small Signal Pulse Response

A_V = 1, V+ = 1.25V, V- = -1.25V



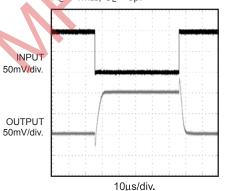
Small Signal Pulse Response

 $A_V = -1$, V + = 2.5V, V - = -2.5V $R_L = 1M\Omega$, $C_L = 8pF$



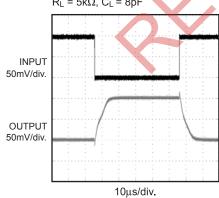
Small Signal Pulse Response

 $A_V = -1$, V + = 1.25V, V - = -1.25V $R_L = 1M\Omega$, $C_L = 8pF$



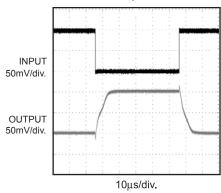
Small Signal Pulse Response

 $A_V = -1$, V+ = 2.5V, V- = -2.5V $R_L = 5k\Omega$, $C_L = 8pF$



Small Signal Pulse Response

 $A_V = -1$, V+ = 1.25V, V- = -1.25V $R_L = 5k\Omega$, $C_L = 8pF$



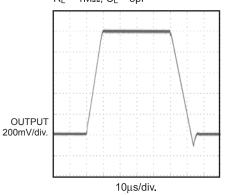


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $T_A = +25$ °C, unless otherwise noted.

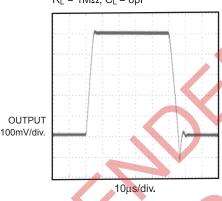


 $A_V = 1$, V+ = 2.5V, V- = -2.5V $R_L = 1M\Omega$, $C_L = 8pF$



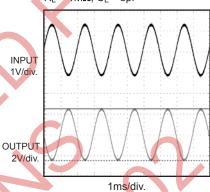
Large Signal Pulse Response

 $A_V = 1$, V+ = 1.25V, V- = -1.25V $R_L = 1M\Omega$, $C_L = 8pF$



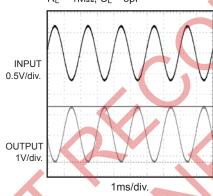
Rail to Rail Output Operation

 $A_V = -2$, V+ = 2.5V, V- = -2.5V R_L = 1M Ω , C_L = 8pF



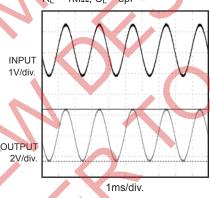
Rail to Rail Output Operation

 $A_V = -2$, V+ = 1.25V, V- = -1.25V $R_L = 1M\Omega$, $C_L = 8pF$



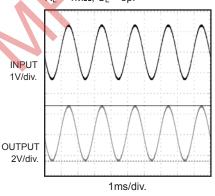
Rail to Rail Output Operation

 $A_V = 2$, V+ = 2.5V, V- = -2.5V $R_L = 1M\Omega$, $C_L = 8pF$



Rail to Rail Output Operation

 $A_V = 2$, V+ = 1.25V, V- = -1.25V $R_L = 1M\Omega$, $C_L = 8pF$



APPLICATION INFORMATION

Power Supply Bypassing

Regular supply bypassing techniques are recommended. A $10\mu F$ capacitor in parallel with a $0.1\mu F$ capacitor on both the positive and negative supplies is ideal. For the best performance, all bypassing capacitors should be located as close to the op amp as possible and all capacitors should be low ESL (Equivalent Series Inductance) and low ESR (Equivalent Series Resistance). Surface mount ceramic capacitors are ideal.